



General Description

Features

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Applications

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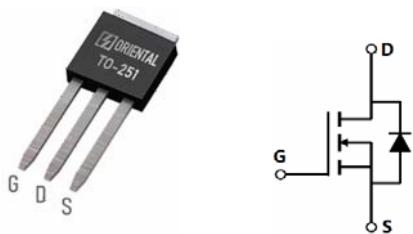
Key Performance Parameters

Parameter	Value	Unit

Marking Information

Product Name	Package	Marking

Package & Pin Information



Absolute Maximum Ratings

Thermal Characteristics

Parameter	Symbol	Value	Unit

Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition



Dynamic Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition

Gate Charge Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition

Body Diode Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition

Note

OS=

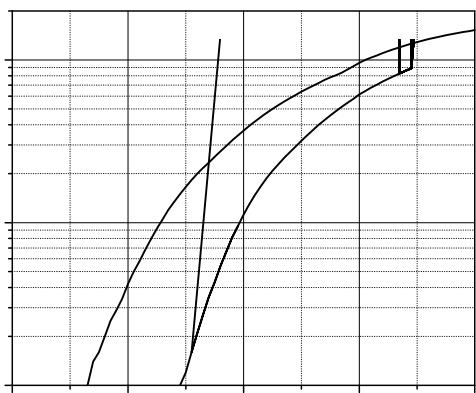


Figure 7. Forward characteristic of body diode

Figure 8. Drain-source on-state resistance

Figure 9. Drain current

Figure 10. Safe operation area $T_c=25\text{ }^\circ\text{C}$

Test circuits and waveforms

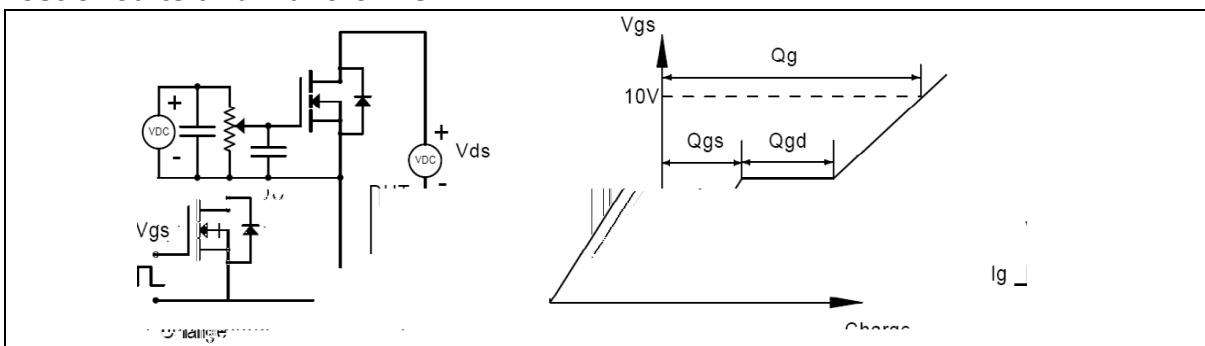


Figure 1. Gate charge test circuit & waveform

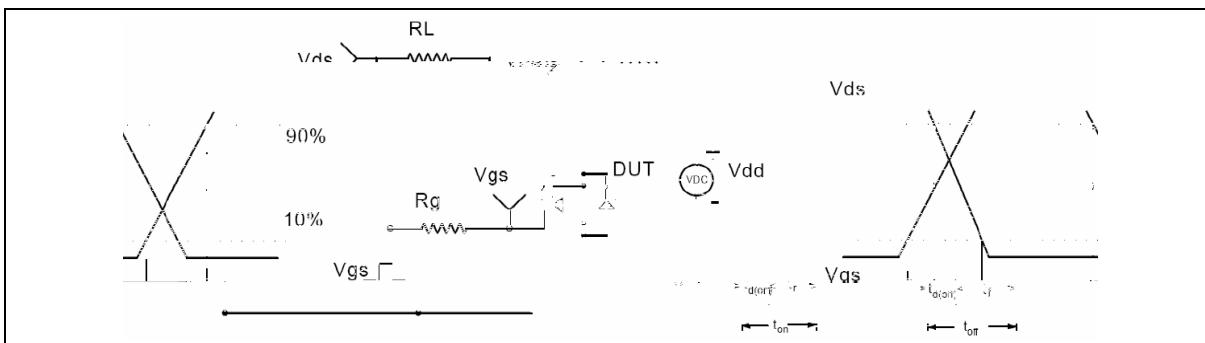


Figure 2. Switching time test circuit & waveforms

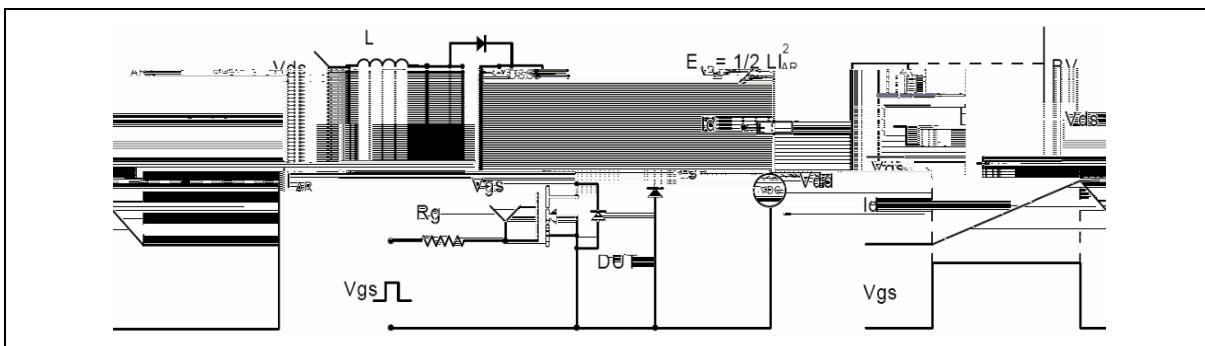


Figure 3. Unclamped inductive switching (UIS) test circuit & waveforms

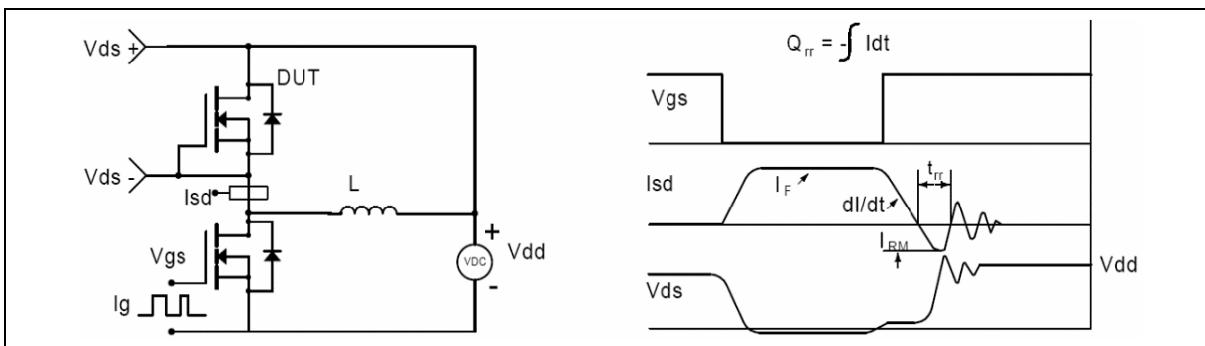


Figure 4. Diode reverse recovery test circuit & waveforms



OSG60R1K2AF



Package Information

Package Type	Units/Reel	Reels / Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box

Product Information

Product	Package	Pb Free	RoHS	Halogen Free

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